

SI3493DV-T1-GE3

SI3493DV-T1-GE3 Information

www.bakemer.com	 SI3493DV-T1-GE3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET P-CH 20V 5.3A 6-TSOP SOT-23-6 Thin, TSOT-23-6 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI3493DV-T1-GE3 Specifications

Manufacturer Part Number	SI3493DV-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	5.3A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs(th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	$\pm 8V$
FET Feature	-
Power Dissipation (Max)	1.1W (Ta)
Rds On (Max) @ Id, Vgs	27 mOhm @ 7A, 4.5V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	6-TSOP
Package / Case	SOT-23-6 Thin, TSOT-23-6
	Report errors?

SI3493DV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3493DV-T1-GE3 Payment Methods



SI3493DV-T1-GE3 Shipping Methods



If you have any question about SI3493DV-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com